# **Switching Transistor**

## **NPN Silicon**

#### Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V <sub>CEO</sub>	12	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	20	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	PD	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

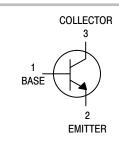
1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



### **ON Semiconductor®**

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SOT-23 (TO-236) CASE 318 STYLE 6

#### MARKING DIAGRAM





M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may

vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

	Device	Package	Shipping <sup>†</sup>
BS	SV52LT1G	SOT–23 (Pb–Free)	3,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

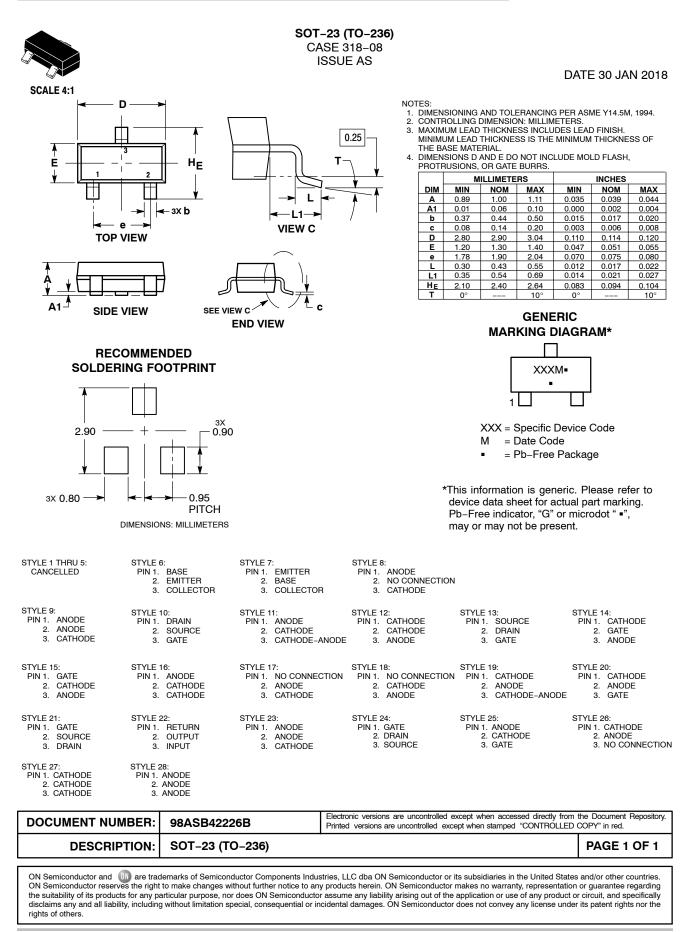
### BSV52LT1G

### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				•
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mAdc)	V <sub>(BR)CEO</sub>	12	_	Vdc
Collector Cutoff Current $(V_{CB} = 10 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 10 \text{ Vdc}, I_E = 0, T_A = 125^{\circ}\text{C})$	Ісво		100 5.0	nAdc μAdc
ON CHARACTERISTICS				
DC Current Gain $(I_C = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ $(I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$ $(I_C = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc})$	H <sub>FE</sub>	25 40 25	_ 120 _	-
$      Collector - Emitter Saturation Voltage \\       (I_C = 10 mAdc, I_B = 300 \ \mu Adc) \\        (I_C = 10 mAdc, I_B = 1.0 mAdc) \\        (I_C = 50 mAdc, I_B = 5.0 mAdc) $	V <sub>CE(sat)</sub>	- - -	300 250 400	mVdc
Base – Emitter Saturation Voltage $(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$	V <sub>BE(sat)</sub>	700 -	850 1200	mVdc
SMALL-SIGNAL CHARACTERISTICS				•
Current-Gain – Bandwidth Product ( $I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 100 \text{ MHz}$ )	f <sub>T</sub>	400	-	MHz
Output Capacitance $(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>obo</sub>	_	4.0	pF
Input Capacitance $(V_{EB} = 1.0 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$	C <sub>ibo</sub>	_	4.5	pF
SWITCHING CHARACTERISTICS				
Storage Time ( $I_C = I_{B1} = I_{B2} = 10 \text{ mAdc}$ )	t <sub>s</sub>	_	13	ns
Turn–On Time $(V_{BE} = 1.5 \text{ Vdc}, I_C = 10 \text{ mAdc}, I_B = 3.0 \text{ mAdc})$	t <sub>on</sub>	_	12	ns
Turn–Off Time ( $I_C = 10 \text{ mAdc}, I_B = 3.0 \text{ mAdc}$ )	t <sub>off</sub>	_	18	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.





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